Unitized Semiconductor Devices - Page 1 of 1



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nclosure Material:	
Plastic	
Overall Length:	
0.375 inches	
Dverall Width:	
0.340 inches	
Component Name And Quantity:	
4 transistor	
Mounting Method: Ferminal	
Features Provided:	
Electrostatic sensitive	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts Per Characteristic:	
30.0 breakdown voltage, collector-to-base, emitter open 4th transistor and 5.0 breakdown v	voltage emitter-to-base collector open 4th
ransistor and 50.0 breakdown voltage, collector-to-emitter, base open 4th transistor	
Current Rating Per Characteristic:	
3.00 amperes collector current, dc all transistor	
Power Rating Per Characteristic:	
10.0 watts total power dissipation 3rd transistor	
Maximum Operating Tempurature Per Measurement Point:	
125.0 degrees celsius junction	
Ferminal Type And Quantity:	
9 pin	
Shelf Life:	
N/a	
Jnit Of Measure:	
-	
Demilitarization:	
Νο	
Filg:	
A110a0	